



Is Now Part of



ON Semiconductor®

To learn more about ON Semiconductor, please visit our website at
www.onsemi.com

ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.



October 2011

FOD3150

High Noise Immunity, 1.0A Output Current, Gate Drive Optocoupler

Features

- High noise immunity characterized by 20kV/ μ s minimum common mode rejection
- Use of P-channel MOSFETs at output stage enables output voltage swing close to the supply rail
- Wide supply voltage range from 15V to 30V
- Fast switching speed
 - 500ns max. propagation delay
 - 300ns max. pulse width distortion
- Under Voltage LockOut (UVLO) with hysteresis
- Extended industrial temperature range, -40°C to 100°C temperature range
- Safety and regulatory approvals
 - UL1577, 5000 V_{RMS} for 1 min.
 - IEC60747-5-2
- >8.0mm clearance and creepage distance (option 'T')

Applications

- Industrial inverter
- Uninterruptible power supply
- Induction heating
- Isolated IGBT/Power MOSFET gate drive

Description

The FOD3150 is a 1.0A Output Current Gate Drive Optocoupler, capable of driving most 800V/20A IGBT/MOSFET. It is ideally suited for fast switching driving of power IGBT and MOSFETs used in motor control inverter applications, and high performance power system.

It utilizes Fairchild's patented coplanar packaging technology, Optoplanar[®], and optimized IC design to achieve high noise immunity, characterized by high common mode rejection.

It consists of a gallium aluminum arsenide (AlGaAs) light emitting diode optically coupled to an integrated circuit with a high-speed driver for push-pull MOSFET output stage.

Related Resources

- FOD3120, 2.5A Output Current, Gate Drive Optocoupler Datasheet
- www.fairchildsemi.com/products/opto/

Functional Block Diagram



Note:

A 0.1 μ F bypass capacitor must be connected between pins 5 and 8.

Package Outlines



FOD3150 — High Noise Immunity, 1.0A Output Current, Gate Drive Optocoupler

Truth Table

LED	$V_{CC}-V_{EE}$ "Positive Going" (Turn-on)	$V_{CC}-V_{EE}$ "Negative Going" (Turn-off)	V_O
Off	0V to 30V	0V to 30V	Low
On	0V to 11V	0V to 9.5V	Low
On	11V to 13.5V	9.5V to 12V	Transition
On	13.5V to 30V	12V to 30V	High

Pin Definitions

Pin #	Name	Description
1	NC	Not Connected
2	Anode	LED Anode
3	Cathode	LED Cathode
4	NC	Not Connected
5	V_{EE}	Negative Supply Voltage
6	V_{O2}	Output Voltage 2 (internally connected to V_{O1})
7	V_{O1}	Output Voltage 1
8	V_{CC}	Positive Supply Voltage

Safety and Insulation Ratings

As per IEC 60747-5-2. This optocoupler is suitable for “safe electrical insulation” only within the safety limit data. Compliance with the safety ratings shall be ensured by means of protective circuits.

Symbol	Parameter	Min.	Typ.	Max.	Unit
	Installation Classifications per DIN VDE 0110/1.89 Table 1				
	For Rated Main Voltage < 150Vrms		I-IV		
	For Rated Main Voltage < 300Vrms		I-IV		
	For Rated Main Voltage < 450Vrms		I-III		
	For Rated Main Voltage < 600Vrms		I-III		
	Climatic Classification		55/100/21		
	Pollution Degree (DIN VDE 0110/1.89)		2		
CTI	Comparative Tracking Index	175			
V_{PR}	Input to Output Test Voltage, Method b, $V_{IORM} \times 1.875 = V_{PR}$, 100% Production Test with $t_m = 1$ sec., Partial Discharge < 5pC	1669			
	Input to Output Test Voltage, Method a, $V_{IORM} \times 1.5 = V_{PR}$, Type and Sample Test with $t_m = 60$ sec., Partial Discharge < 5 pC	1335			
V_{IORM}	Max Working Insulation Voltage	890			V_{peak}
V_{IOTM}	Highest Allowable Over Voltage	6000			V_{peak}
	External Creepage	8			mm
	External Clearance	7.4			mm
	External Clearance (for Option T-0.4" Lead Spacing)	10.16			mm
	Insulation Thickness	0.5			mm
T_{Case}	Safety Limit Values – Maximum Values Allowed in the Event of a Failure				
	Case Temperature	150			°C
$I_{S,INPUT}$	Input Current	25			mA
$P_{S,OUTPUT}$	Output Power (Duty Factor $\leq 2.7\%$)	250			mW
R_{IO}	Insulation Resistance at T_S , $V_{IO} = 500V$	10^9			Ω

Absolute Maximum Ratings ($T_A = 25^\circ\text{C}$ unless otherwise specified)

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Value	Units
T_{STG}	Storage Temperature	-55 to +125	$^\circ\text{C}$
T_{OPR}	Operating Temperature	-40 to +100	$^\circ\text{C}$
T_J	Junction Temperature	-40 to +125	$^\circ\text{C}$
T_{SOL}	Lead Wave Solder Temperature (refer to page 19 for reflow solder profile)	260 for 10sec	$^\circ\text{C}$
$I_{F(AVG)}$	Average Input Current	25	mA
V_R	Reverse Input Voltage	5	V
$I_{O(PEAK)}$	Peak Output Current ⁽¹⁾	1.5	A
$V_{CC} - V_{EE}$	Supply Voltage	0 to 35	V
$V_{O(PEAK)}$	Peak Output Voltage	0 to V_{CC}	V
$t_{R(IN)}, t_{F(IN)}$	Input Signal Rise and Fall Time	500	ns
PD_I	Input Power Dissipation ⁽²⁾⁽⁴⁾	45	mW
PD_O	Output Power Dissipation ⁽³⁾⁽⁴⁾	250	mW

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to absolute maximum ratings.

Symbol	Parameter	Value	Units
T_A	Ambient Operating Temperature	-40 to +100	$^\circ\text{C}$
$V_{CC} - V_{EE}$	Power Supply	15 to 30	V
$I_{F(ON)}$	Input Current (ON)	7 to 16	mA
$V_{F(OFF)}$	Input Voltage (OFF)	0 to 0.8	V

Isolation Characteristics

Apply over all recommended conditions, typical value is measured at $T_A = 25^\circ\text{C}$

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
V_{ISO}	Input-Output Isolation Voltage	$T_A = 25^\circ\text{C}$, R.H. < 50%, $t = 1.0\text{min}$, $I_{I-O} \leq 10\mu\text{A}$, 50Hz ⁽⁵⁾⁽⁶⁾	5000			V_{RMS}
R_{ISO}	Isolation Resistance	$V_{I-O} = 500\text{V}^{(5)}$		10^{11}		Ω
C_{ISO}	Isolation Capacitance	$V_{I-O} = 0\text{V}$, Freq = 1.0MHz ⁽⁵⁾		1		pF

Electrical Characteristics

Apply over all recommended conditions, typical value is measured at $V_{CC} = 30V$, $V_{EE} = \text{Ground}$, $T_A = 25^\circ\text{C}$ unless otherwise specified.

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
V_F	Input Forward Voltage	$I_F = 10\text{mA}$	1.2	1.5	1.8	V
$\Delta(V_F / T_A)$	Temperature Coefficient of Forward Voltage			-1.8		mV/°C
BV_R	Input Reverse Breakdown Voltage	$I_R = 10\mu\text{A}$	5			V
C_{IN}	Input Capacitance	$f = 1\text{MHz}$, $V_F = 0V$		60		pF
I_{OH}	High Level Output Current ⁽¹⁾	$V_O = V_{CC} - 0.75V$	0.2			A
		$V_O = V_{CC} - 4V$	1.0			
I_{OL}	Low Level Output Current ⁽¹⁾	$V_O = V_{CC} + 0.75V$	0.2			A
		$V_O = V_{CC} + 4V$	1.0			
V_{OH}	High Level Output Voltage	$I_F = 10\text{mA}$, $I_O = -1\text{A}$	$V_{CC} - 4V$	$V_{CC} - 6V$		V
		$I_F = 10\text{mA}$, $I_O = -100\text{mA}$	$V_{CC} - 0.5V$	$V_{CC} - 0.1V$		
V_{OL}	Low Level Output Voltage	$I_F = 0\text{mA}$, $I_O = 1\text{A}$		$V_{EE} + 6V$	$V_{EE} + 4V$	V
		$I_F = 0\text{mA}$, $I_O = 100\text{mA}$		$V_{EE} + 0.1V$	$V_{EE} + 0.5V$	
I_{CCH}	High Level Supply Current	$V_O = \text{Open}$, $I_F = 7$ to 16mA		2.8	5	mA
I_{CCL}	Low Level Supply Current	$V_O = \text{Open}$, $V_F = 0$ to $0.8V$		2.8	5	mA
I_{FLH}	Threshold Input Current Low to High	$I_O = 0\text{mA}$, $V_O > 5V$		2.3	5.0	mA
V_{FHL}	Threshold Input Voltage High to Low	$I_O = 0\text{mA}$, $V_O < 5V$	0.8			V
V_{UVLO+}	Under Voltage Lockout Threshold	$I_F = 10\text{mA}$, $V_O > 5V$	11	12.7	13.5	V
V_{UVLO-}		$I_F = 10\text{mA}$, $V_O < 5V$	9.5	11.2	12.0	V
$UVLO_{HYS}$	Under Voltage Lockout Threshold Hysteresis			1.5		V

Switching Characteristics

Apply over all recommended conditions, typical value is measured at $V_{CC} = 30V$, $V_{EE} = \text{Ground}$, $T_A = 25^\circ\text{C}$ unless otherwise specified.

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
t_{PHL}	Propagation Delay Time to Logic Low Output	$I_F = 7\text{mA to } 16\text{mA}$, $R_G = 20\Omega$, $C_G = 10\text{nF}$, $f = 10\text{kHz}$, Duty Cycle = 50%	100	275	500	ns
t_{PLH}	Propagation Delay Time to Logic High Output		100	255	500	ns
PWD	Pulse Width Distortion, $ t_{PHL} - t_{PLH} $			20	300	ns
PDD (Skew)	Propagation Delay Difference Between Any Two Parts or Channels, $(t_{PHL} - t_{PLH})^{(7)}$			-350	350	ns
t_r	Output Rise Time (10% – 90%)				60	ns
t_f	Output Fall Time (90% – 10%)				60	ns
$t_{UVLO\ ON}$	UVLO Turn On Delay		$I_F = 10\text{mA}$, $V_O > 5V$		1.6	
$t_{UVLO\ OFF}$	UVLO Turn Off Delay	$I_F = 10\text{mA}$, $V_O < 5V$		0.4		μs
$ CM_H $	Common Mode Transient Immunity at Output High	$T_A = 25^\circ\text{C}$, $V_{CC} = 30V$, $I_F = 7 \text{ to } 16\text{mA}$, $V_{CM} = 2000V^{(8)}$	20	50		$\text{kV}/\mu\text{s}$
$ CM_L $	Common Mode Transient Immunity at Output Low	$T_A = 25^\circ\text{C}$, $V_{CC} = 30V$, $V_F = 0V$, $V_{CM} = 2000V^{(9)}$	20	50		$\text{kV}/\mu\text{s}$

Notes:

- Maximum pulse width = $10\mu\text{s}$, maximum duty cycle = 0.2%
- Derate linearly above 87°C , free air temperature at a rate of $0.77\text{mW}/^\circ\text{C}$
- No derating required across temperature range.
- Functional operation under these conditions is not implied. Permanent damage may occur if the device is subjected to conditions outside these ratings.
- Device is considered a two terminal device: Pins 2 and 3 are shorted together and Pins 5, 6, 7 and 8 are shorted together.
- $5,000 V_{RMS}$ for 1 minute duration is equivalent to $6,000 VAC_{RMS}$ for 1 second duration.
- The difference between t_{PHL} and t_{PLH} between any two FOD3150 parts under same test conditions.
- Common mode transient immunity at output high is the maximum tolerable negative dV_{cm}/dt on the trailing edge of the common mode impulse signal, V_{cm} , to assure that the output will remain high (i.e. $V_O > 15.0V$).
- Common mode transient immunity at output low is the maximum tolerable positive dV_{cm}/dt on the leading edge of the common pulse signal, V_{cm} , to assure that the output will remain low (i.e. $V_O < 1.0V$).

Typical Performance Curves

Fig. 1 Output High Voltage Drop vs. Output High Current

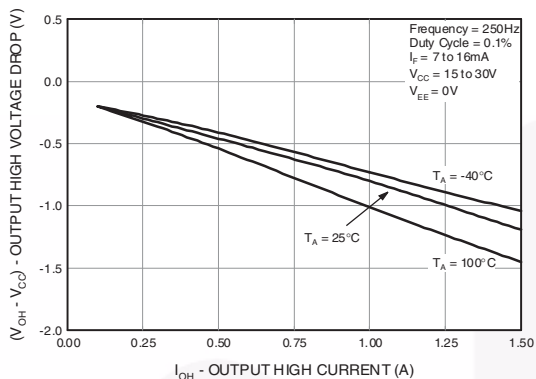


Fig. 2 Output High Voltage Drop vs. Ambient Temperature



Fig. 3 Output Low Voltage vs. Output Low Current

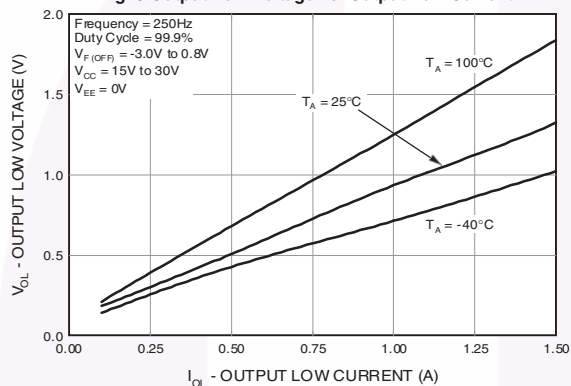


Fig. 4 Output Low Voltage vs. Ambient Temperature



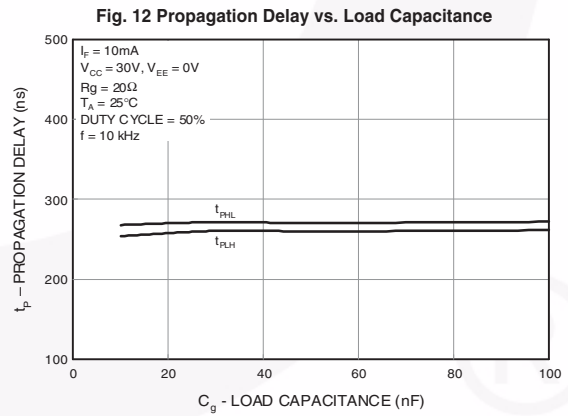
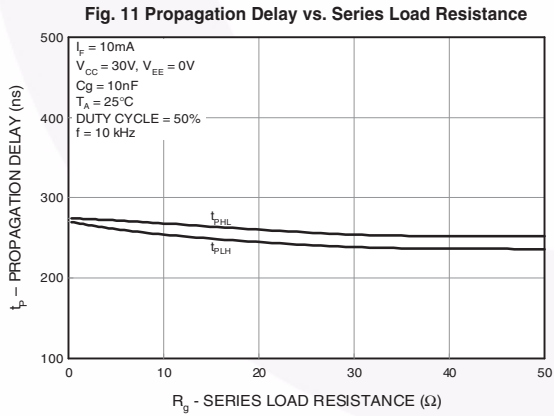
Fig. 5 Supply Current vs. Ambient Temperature



Fig. 6 Supply Current vs. Supply Voltage



Typical Performance Curves (Continued)



Typical Performance Curves (Continued)

Fig. 13 Transfer Characteristics



Fig. 14 Input Forward Current vs. Forward Voltage

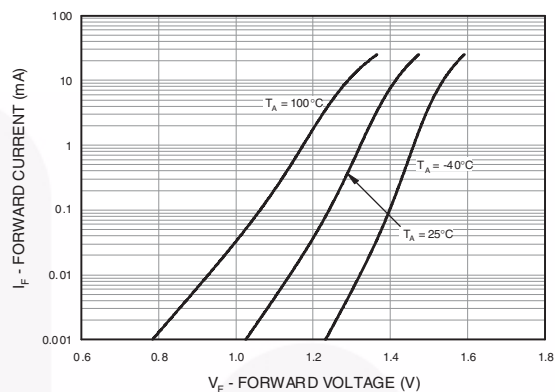


Fig. 15 Under Voltage Lockout



Test Circuit



Figure 20. I_{OL} Test Circuit

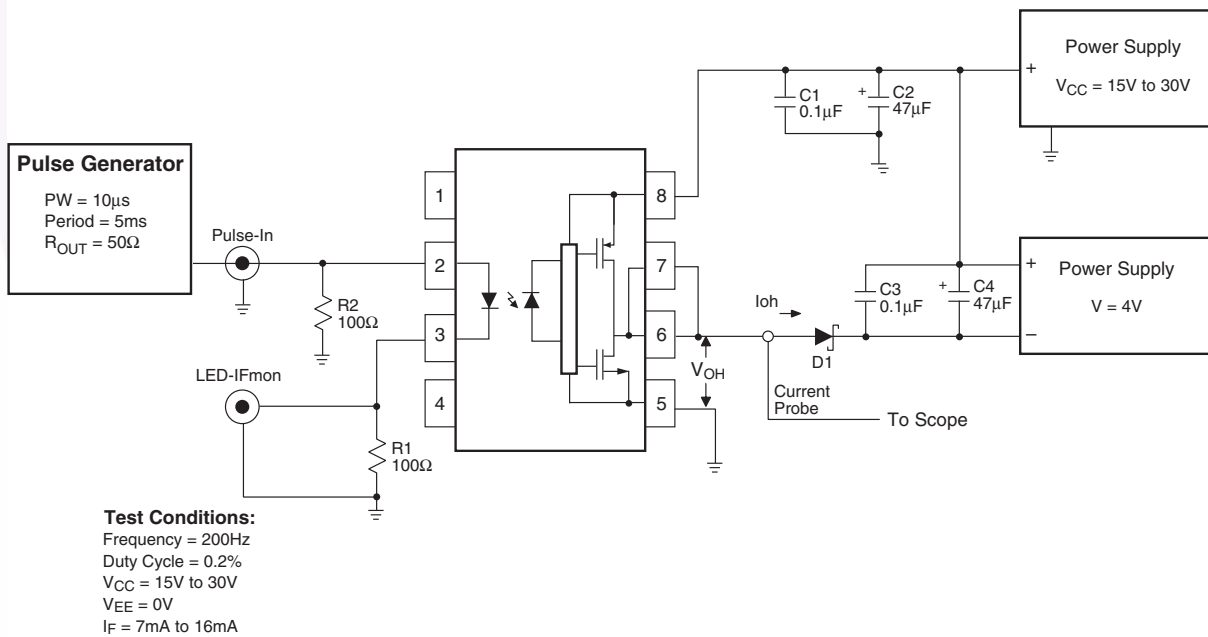


Figure 21. I_{OH} Test Circuit

Test Circuit (Continued)



Figure 22. V_{OH} Test Circuit



Figure 23. V_{OL} Test Circuit



Test Circuit (Continued)



Figure 24. I_{CCH} Test Circuit



Figure 25. I_{CCL} Test Circuit



Test Circuit (Continued)

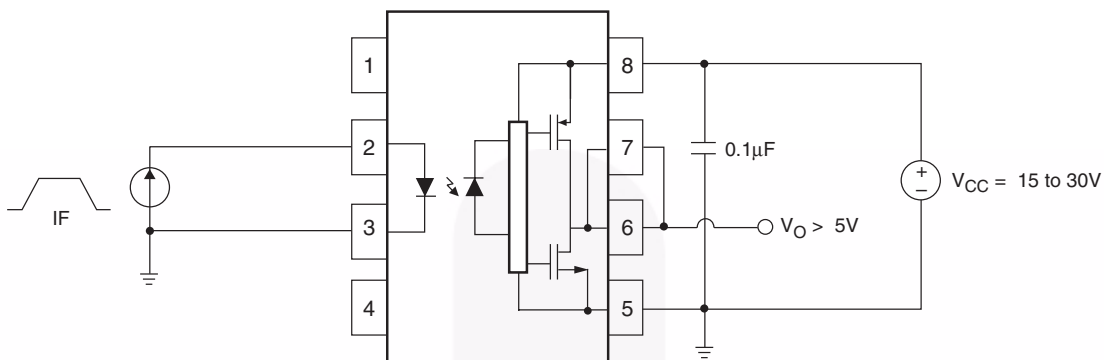


Figure 26. I_{FLH} Test Circuit



Figure 27. V_{FHL} Test Circuit



Figure 28. UVLO Test Circuit

Test Circuit (Continued)



Figure 29. t_{PHL} , t_{PLH} , t_R and t_F Test Circuit and Waveforms



Figure 30. CMR Test Circuit and Waveforms

Ordering Information

Part Number	Package	Packing Method
FOD3150	DIP 8-Pin	Tube (50 units per tube)
FOD3150S	SMT 8-Pin (Lead Bend)	Tube (50 units per tube)
FOD3150SD	SMT 8-Pin (Lead Bend)	Tape and Reel (1,000 units per reel)
FOD3150V	DIP 8-Pin, IEC60747-5-2 option	Tube (50 units per tube)
FOD3150SV	SMT 8-Pin (Lead Bend), IEC60747-5-2 option	Tube (50 units per tube)
FOD3150SDV	SMT 8-Pin (Lead Bend), IEC60747-5-2 option	Tape and Reel (1,000 units per reel)
FOD3150T	DIP 8-Pin, 0.4" Lead Spacing	Tube (50 units per tube)
FOD3150TV	DIP 8-Pin, 0.4" Lead Spacing , IEC60747-5-2 option	Tube (50 units per tube)

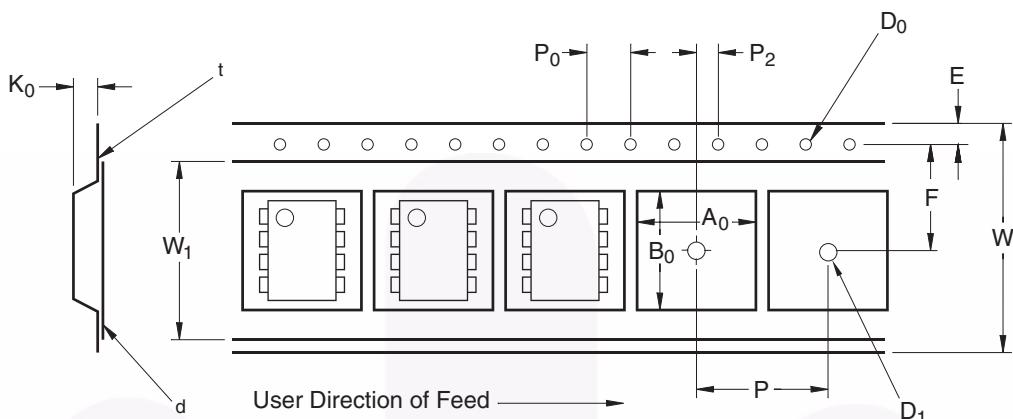
Marking Information



Definitions

1	Fairchild logo
2	Device number
3	IEC60747-5-2 Option (only appears on component ordered with this option)
4	Two digit year code, e.g., '08'
5	Two digit work week ranging from '01' to '53'
6	Assembly package code

Carrier Tape Specifications



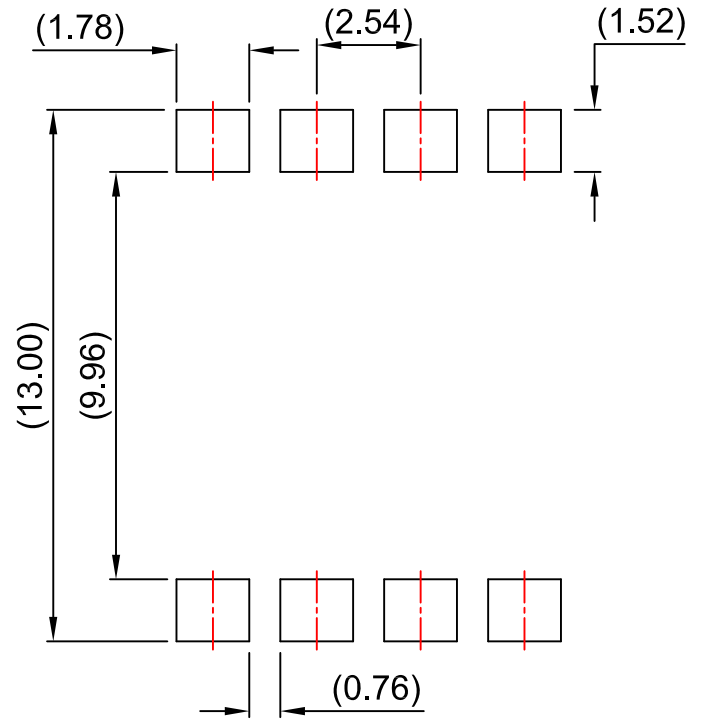
Symbol	Description	Dimension in mm
W	Tape Width	16.0 ± 0.3
t	Tape Thickness	0.30 ± 0.05
P_0	Sprocket Hole Pitch	4.0 ± 0.1
D_0	Sprocket Hole Diameter	1.55 ± 0.05
E	Sprocket Hole Location	1.75 ± 0.10
F	Pocket Location	7.5 ± 0.1
P_2		2.0 ± 0.1
P	Pocket Pitch	12.0 ± 0.1
A_0	Pocket Dimensions	10.30 ± 0.20
B_0		10.30 ± 0.20
K_0		4.90 ± 0.20
W_1	Cover Tape Width	13.2 ± 0.2
d	Cover Tape Thickness	0.1 max
	Max. Component Rotation or Tilt	10°
R	Min. Bending Radius	30

Reflow Profile

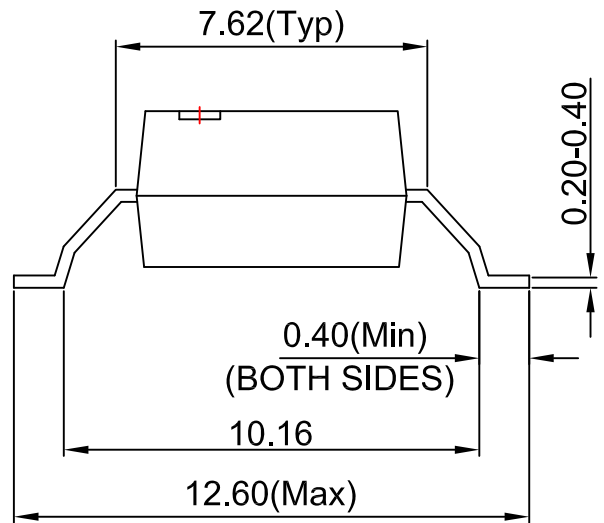


- Peak reflow temperature: 260C (package surface temperature)
- Time of temperature higher than 183C for 160 seconds or less
- One time soldering reflow is recommended





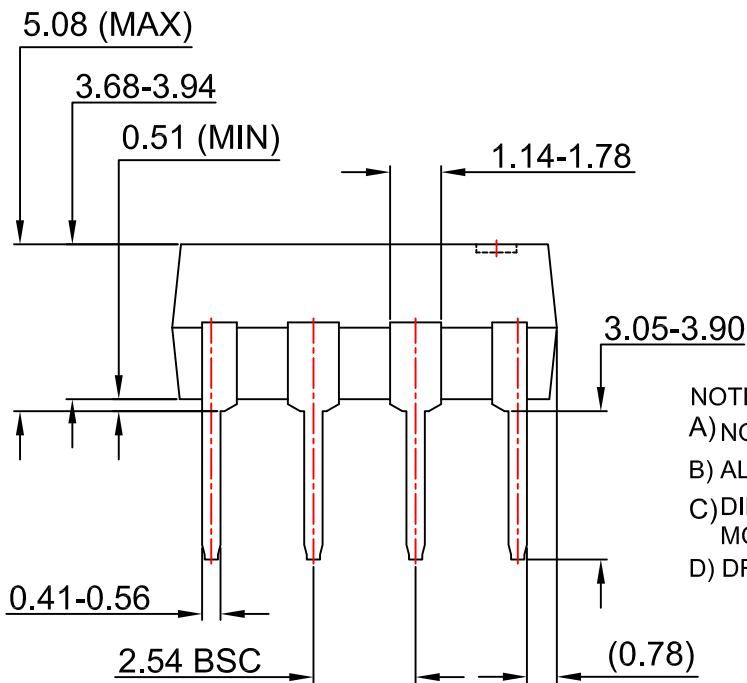
LAND PATTERN RECOMMENDATION



NOTES:

- A) NO STANDARD APPLIES TO THIS PACKAGE
- B) ALL DIMENSIONS ARE IN MILLIMETERS.
- C) DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSION
- D) DWG FILENAME AND REVISION: MKT-N08Lrev2.





- NOTES:
 A) NO STANDARD APPLIES TO THIS PACKAGE
 B) ALL DIMENSIONS ARE IN MILLIMETERS.
 C) DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSION
 D) DRAWING FILENAME AND REVISION: MKT-N08GREV7





LAND PATTERN RECOMMENDATION



NOTES:

- A) NO STANDARD APPLIES TO THIS PACKAGE
- B) ALL DIMENSIONS ARE IN MILLIMETERS.
- C) DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSION
- D) DRAWING FILENAME AND REVISION: MKT-N08Hrev7.





PIN 1

15.0° (MAX)

10.16 (TYP)

0.20-0.40



NOTES:

- A) NO STANDARD APPLIES TO THIS PACKAGE
- B) ALL DIMENSIONS ARE IN MILLIMETERS.
- C) DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSION
- D) DRAWING FILENAME AND REVISION: MKT-N08REV7





TRADEMARKS

The following includes registered and unregistered trademarks and service marks, owned by Fairchild Semiconductor and/or its global subsidiaries, and is not intended to be an exhaustive list of all such trademarks.

- AccuPower™
- AttitudeEngine™
- Awinda®
- AX-CAP®*
- BitSiC™
- Build it Now™
- CorePLUS™
- CorePOWER™
- CROSSVOL™
- CTL™
- Current Transfer Logic™
- DEUXPEED®
- Dual Cool™
- EcoSPARK®
- EfficientMax™
- ESBC™
- F**™
- Fairchild®
- Fairchild Semiconductor®
- FACT Quiet Series™
- FACT®
- FastvCore™
- FETBench™
- FPS™
- F-PFS™
- FRFET®
- Global Power ResourceSM
- GreenBridge™
- Green FPS™
- Green FPS™ e-Series™
- Gmax™
- GTO™
- IntelliMAX™
- ISOPLANAR™
- Making Small Speakers Sound Louder and Better™
- MegaBuck™
- MICROCOUPLER™
- MicroFET™
- MicroPak™
- MicroPak2™
- MillerDrive™
- MotionMax™
- MotionGrid®
- MTi®
- MTx®
- MVN®
- mWSaver®
- OptoHiT™
- OPTOLOGIC®
- OPTOPLANAR®
- ®
- Power Supply WebDesigner™
- PowerTrench®
- PowerXS™
- Programmable Active Droop™
- QFET®
- QS™
- Quiet Series™
- RapidConfigure™
- ™
- Saving our world, 1mW/W/kW at a time™
- SignalWise™
- SmartMax™
- SMART START™
- Solutions for Your Success™
- SPM®
- STEALTH™
- SuperFET®
- SuperSOT™-3
- SuperSOT™-6
- SuperSOT™-8
- SupreMOS®
- SyncFET™
- Sync-Lock™
- ®
- TinyBoost®
- TinyBuck®
- TinyCalc™
- TinyLogic®
- TINYOPTO™
- TinyPower™
- TinyPWM™
- TinyWire™
- TranSiC™
- TriFault Detect™
- TRUECURRENT®*
- μSerDes™
- ™
- UHC®
- Ultra FRFET™
- UniFET™
- VcX™
- VisualMax™
- VoltagePlus™
- XS™
- Xsens™
- 仙童®

* Trademarks of System General Corporation, used under license by Fairchild Semiconductor.

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. TO OBTAIN THE LATEST, MOST UP-TO-DATE DATASHEET AND PRODUCT INFORMATION, VISIT OUR WEBSITE AT [HTTP://WWW.FAIRCHILDSEMI.COM](http://www.fairchildsemi.com). FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

AUTHORIZED USE

Unless otherwise specified in this data sheet, this product is a standard commercial product and is not intended for use in applications that require extraordinary levels of quality and reliability. This product may not be used in the following applications, unless specifically approved in writing by a Fairchild officer: (1) automotive or other transportation, (2) military/aerospace, (3) any safety critical application – including life critical medical equipment – where the failure of the Fairchild product reasonably would be expected to result in personal injury, death or property damage. Customer's use of this product is subject to agreement of this Authorized Use policy. In the event of an unauthorized use of Fairchild's product, Fairchild accepts no liability in the event of product failure. In other respects, this product shall be subject to Fairchild's Worldwide Terms and Conditions of Sale, unless a separate agreement has been signed by both Parties.

ANTI-COUNTERFEITING POLICY

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Fairchild's Anti-Counterfeiting Policy is also stated on our external website, www.fairchildsemi.com, under Terms of Use

Counterfeiting of semiconductor parts is a growing problem in the industry. All manufacturers of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed applications, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handling and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address any warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.

Rev. I77